FREE

Vishay Semiconductors

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Hyperfast Rectifier, 15 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES

A

30 3D Models



PRIMARY CHARACTERISTICS						
I _{F(AV)} 15 A						
V _R	1200 V					
V _F at I _F at 125 °C	2.1 V					
t _{rr}	29 ns					
T _J max.	175 °C					
Package	TO-220AC 2L					
Circuit configuration	Single					

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching RoHS losses trade off COMPLIANT HALOGEN
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

Polarity: as per marking device details

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V _{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 98 °C, D = 0.50	15				
Repetitive peak forward current	I _{FRM}	T _C = 98 °C, D = 0.50, f = 20 kHz	30	А			
Non-repetitive peak surge current	I _{FSM}	T_{C} = 45 °C, t_{p} = 10 ms, sine wave	110				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	MBOL TEST CONDITIONS MIN. TYP. M				UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	1200	-	-			
Forward voltage	V _F	I _F = 15 A	-	2.5	3.3	V		
		I _F = 15 A, T _J = 125 °C	-	2.1	-			
	I _R	$V_{R} = V_{R}$ rated	-	-	50	uА		
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500			
Junction capacitance	CT	V _R = 200 V	-	10	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		

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DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ d}I_F/$	I _F = 1.0 A, dI _F /dt = 100 A/µs, V _R = 30 V		29	44			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	96	-	ns		
		T _J = 125 °C		-	137	-			
Peak recovery current	I _{RRM}	T _J = 25 °C	$I_{\rm F} = 10 {\rm A}$	-	11.5	-	A		
Feak recovery current		T _J = 125 °C	dl _F /dt = 600 A/µs V _R = 400 V	-	16	-			
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	375	-	nC		
Reverse recovery charge		T _J = 125 °C		-	900	-			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	77.5	-	ns		
neverse recovery time	۲r	T _J = 125 °C		-	106	-	115		
Pook receivery ourrent	I _{RRM}	T _J = 25 °C	I _F = 15 A dI _F /dt = 1000 A/μs V _B = 800 V	-	21	-	A		
Peak recovery current		T _J = 125 °C		-	29	-			
	0	T _J = 25 °C		-	680	-			
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1600	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.7	°C/W		
Weight			-	2.0	-	g		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style TO-220AC 2L	E5TX1512					

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VS-E5TX1512-M3

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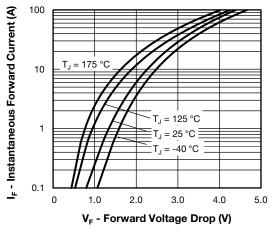


Fig. 1 - Forward Voltage Drop Characteristics

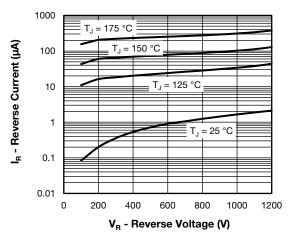


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

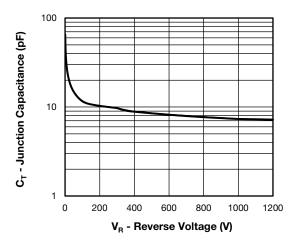


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

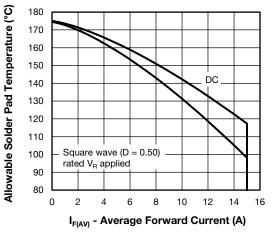


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

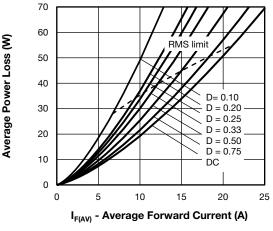


Fig. 5 - Forward Power Loss Characteristics

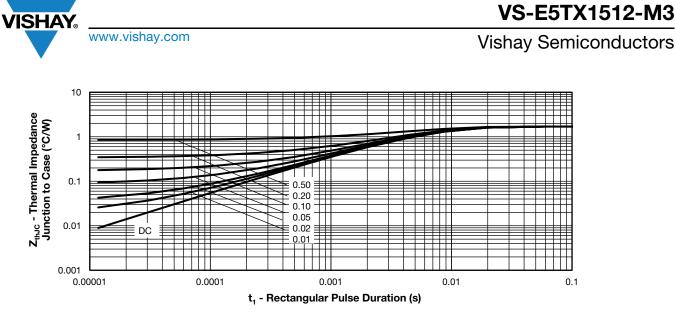
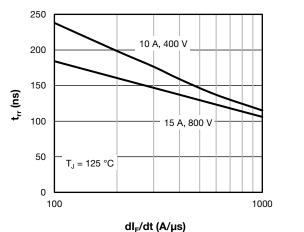
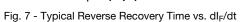


Fig. 6 - Transient Thermal Impedance, Junction to Case





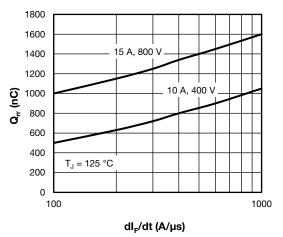


Fig. 8 - Typical Stored Charge vs. dl_F/dt

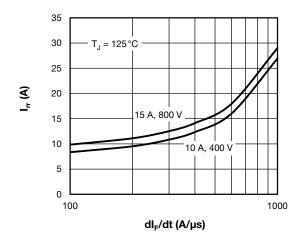
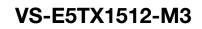


Fig. 9 - Typical Recovery Current vs. dI_F/dt





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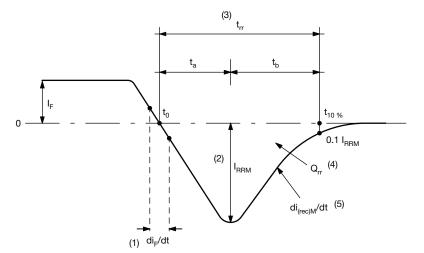


Fig. 10 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- ⁽³⁾ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}~~Q_{rr}$ area under curve defined by t_0 and $t_{10}~\%$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

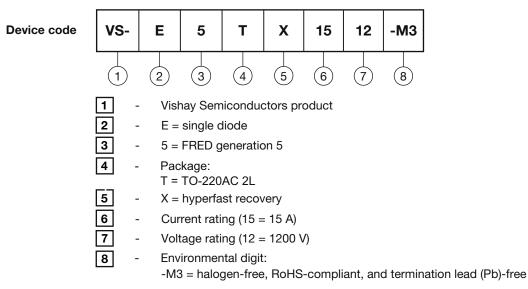
 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

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ORDERING INFORMATION TABLE

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ORDERING INFORMATION (Example)						
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION						
VS-E5TX1512-M3	50	Antistatic plastic tubes				

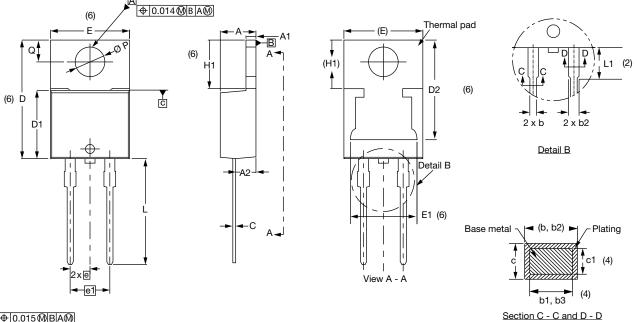
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96156				
Part marking information	www.vishay.com/doc?95391				
SPICE Model	www.vishay.com/doc?97160				



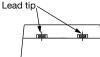
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TO-220AC 2L

DIMENSIONS in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	MILLIMETERS		INCHES			
STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES		
D2	11.68	13.30	0.460	0.524	6, 7		
E	10.11	10.51	0.398	0.414	3, 6		
E1	6.86	8.89	0.270	0.350	6		
е	2.41	2.67	0.095	0.105			
e1	4.88	5.28	0.192	0.208			
H1	6.09	6.48	0.240	0.255	6		
L	13.52	14.02	0.532	0.552			
L1	3.32	3.82	0.131	0.150	2		
ØР	3.54	3.91	0.139	0.154			
Q	2.60	3.00	0.102	0.118			

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1

⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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